TOPTICA

EYP-RWL-0808-00800-4000-BFW09-0000

Revision 1.00

SINGLE MODE LASER DIODES Fabry-Perot Laser



General Product Information

| Application |
|-------------|
| Metrology |
| |
| |
| |
| |



Absolute Maximum Ratings

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------------|----------------|------|-----|-----|-----|
| Storage Temperature | T _S | °C | -40 | | 85 |
| Operational Temperature at Case | T_{C} | °C | -20 | | 75 |
| Operational Temperature at Laser Chip | T_LD | °C | 10 | | 40 |
| Forward Current | I _F | А | | | 1.6 |
| Reverse Voltage | V_R | V | | | 2 |
| Output Power | P_{opt} | mW | | | 900 |
| TEC Current | I_{TEC} | Α | | | 1.5 |
| TEC Voltage | V_{TEC} | V | | | 5.5 |

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings can cause permanent damage to the device. Do not exceed the maximum optical output power or maximum forward current, whichever occurs first.

Recommended Operational Conditions

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------------|------------------|------|-----|-----|-----|
| Operational Temperature at Case | T _C | °C | 0 | | 40 |
| Operational Temperature at Laser Chip | T_{LD} | °C | 20 | 25 | 30 |
| Forward Current | I _F | Α | | 1.0 | 1.5 |
| Output Power | P_{opt} | mW | | | 800 |

Characteristics at T_{LD} = 25° C at Begin Of Life

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------------|------------------|--------|-----|------|-----|
| Center Wavelength | λ_{C} | nm | 796 | 808 | 816 |
| Spectral Width (FWHM) | $\Delta\lambda$ | nm | | 1 | 3 |
| Temperature Coefficient of Wavelength | dλ / dT | nm / K | | 0.28 | |
| Threshold Current | I_{th} | А | | | 0.3 |
| Output Power @ $I_F = 1.5 A$ | P _{opt} | mW | 800 | | |

| Measurement Conditions / Comment | S |
|----------------------------------|---|
|----------------------------------|---|

 $P_{\rm opt} = 800$ mW, multi mode emission



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Characteristics at T_{LD} = 25° C at Begin Of Life

| Symbol | Unit | min | typ | max |
|----------------------------------|---|--|--|---|
| $\Theta_{ }$ | 0 | | 0.1 | 0.15 |
| Θ_{\perp} | 0 | | 0.1 | 0.15 |
| Θ_{\perp} / $\Theta_{ }$ | | 0.66 | | 1.5 |
| d | mm | | 1 | 1.5 |
| d_\perp | mm | | 1 | 1.5 |
| $d_{ }/d_{\perp}$ | | 0.66 | | 1.5 |
| M^2 | | | 1.2 | 1.5 |
| DOP | % | | 90 | |
| | Θ_{\perp} $\Theta_{\perp} / \Theta_{ }$ $d_{ }$ d_{\perp} $d_{ } / d_{\perp}$ M^{2} | $\begin{array}{ccc} \Theta_{ } & \circ & \\ \Theta_{\perp} / \Theta_{ } & \\ d_{ } & mm \\ d_{\perp} & mm \\ d_{ } / d_{\perp} & \\ M^2 & \end{array}$ | $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

| ull angle, para | llel to base plate (see p. 3) |
|------------------|------------------------------------|
| full angle, perp | endicular to base plate (see p. 3) |
| parallel to base | e plate (see p. 3) |
| | to base plate (see p. 3) |
| | |
| | |
| E field perpend | icular to base plate (see p. 3) |



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Thermistor (Standard NTC Type)



| Monitor Diode | | | | | |
|-------------------------------|------------------|------|-----|-----|------|
| Parameter | Symbol | Unit | min | typ | max |
| Monitor Detector Responsivity | I _{mon} | μΑ | 10 | 7. | 1000 |

| Measurement Conditions / Comments |
|--|
| $U_R = 5 \text{ V; } P_{opt} = 800 \text{ mW}$ |

| Parameter | Symbol | Unit | min | typ | max |
|--|-------------------|------|-----|-----|-----|
| Current | I _{TEC} | А | 0.3 | 0.9 | 1.5 |
| Voltage | U_TEC | V | 1.0 | 4 | 5.5 |
| Power Dissipation (total loss at case) | P _{loss} | W | 1.8 | 2.1 | 2.5 |
| Temperature Difference | ΔΤ | K | | | 30 |

| Measurement Conditions / Comme | nts |
|--|-----|
| Popt = 800 mW, $\Delta T = 30 \text{ K}$ | |
| $P_{opt} = 800 \text{ mW}, \Delta T = 30 \text{ K}$ | |
| $P_{opt} = 800 \text{ mW}, \Delta T = 30 \text{ K}$ | |
| $P_{opt} = 800 \text{ mW}, \ \Delta T = I \ T_{case} - T_{LD} \ I$ | |

| Parameter | Symbol | Unit | min | typ | max |
|------------------------------|--------|------|-----|---------------------------|-----|
| Resistance | R | kΩ | | 10 | |
| Beta Coefficient | β | | | 3892 | |
| Steinhart & Hart Coefficient | А | | | 1.1293 x 10 ⁻¹ | 3 |
| Steinhart & Hart Coefficient | В | | 2 | 2.3410 x 10 | 4 |
| Steinhart & Hart Coefficient | С | | 8 | 3.7755 x 10 ⁻¹ | 8 |

| Measurement Conditions / Comments | | |
|---|--|--|
| T = 25° C | | |
| $R_1 / R_2 = e^{\beta (1/T_1 - 1/T_2)}$ at $T = 0^{\circ} \dots 50^{\circ} C$ | | |
| $1/T = A + B(\ln R) + C(\ln R)^3$ | | |
| T: temperature in Kelvin | | |
| R: resistance at T im Ohm | | |
| | | |



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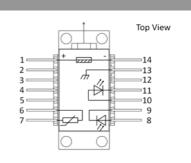
| Package | e D | imer | nsion | S |
|---------|-----|------|-------|---|
| | | | | |

| Parameter | Symbol | Unit | min | typ | max |
|--------------------------|-----------------|------|-----|-----|-----|
| Height of Emission Plane | h _{EP} | mm | | 4.9 | |

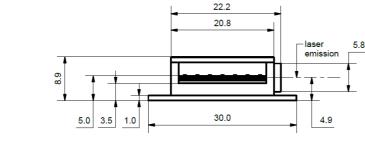
Measurement Conditions / Comments

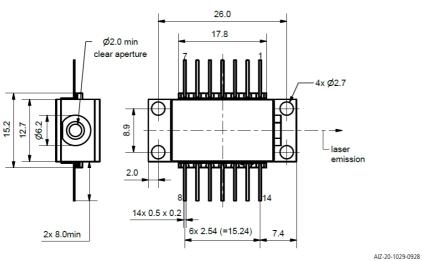
Package Pinout

| 1 | Thermoelectric Cooler (+) | 14 | Thermoelectric Cooler (-) |
|---|---------------------------|----|---------------------------|
| 2 | not connected | 13 | Case |
| 3 | not connected | 12 | not connected |
| 4 | not connected | 11 | Laser Diode (Cathode) |
| 5 | not connected | 10 | Laser Diode (Anode) |
| 6 | Thermistor | 9 | Photodiode (Anode) |
| 7 | Thermistor | 8 | Photodiode (Cathode) |
| | | | |



Package Drawings





Polarization:

E field perpendicular to base plate



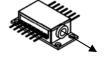
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Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Laser Emission



Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.









vith 21 CFR 1040.10 and 1040.40

